# NSN 5961-00-780-1987

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**Inclosure Material:** 

Metal

**Overall Length:** 

0.450 inches

#### **Overall Diameter:**

0.875 inches

# **Mounting Facility Quantity:**

2

# Internal Configuration:

Point contact

# Electrode Internally-electrically Connected To Case:

Collector

#### **Mounting Method:**

Unthreaded hole

#### Features Provided:

Hermetically sealed case

## Semiconductor Material:

Germanium

## Voltage Rating In Volts Per Characteristic:

80.0 breakdown voltage, collector-to-base, emitter open and 40.0 breakdown voltage, collector-to-emitter, base open and 40.0

breakdown voltage, emitter-to-base, collector open

## **Current Rating Per Characteristic:**

25.00 amperes source cutoff current

#### Maximum Operating Tempurature Per Measurement Point:

100.0 degrees celsius case

#### **Special Features:**

Junction pattern arrangement: pnp

#### **Terminal Type And Quantity:**

2 uninsulated wire lead and 1 case

#### **Specification Data:**

80131-release2995 professional/industrial association specification

Shelf Life:

N/a

#### Unit Of Measure:

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#### Demilitarization:

No

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